

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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MA3D799 (MA10799)

Silicon epitaxial planar type (cathode common)

For switching mode power supply

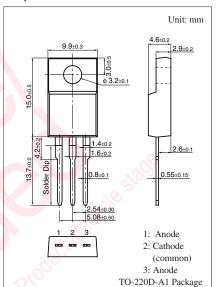
■ Features

- Forward current (Average) $I_{F(AV)} = 10$ A rectification is possible
- Cathode-common dual type
- Low forward voltage: $V_F < 0.47 \text{ V}$

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit	
Repetitive peak reverse voltage	V _{RRM}	30	V	
Forward current (Average)	I _{F(AV)}	10	A	
Non-repetitive peak forward	I _{FSM}	120	A	
surge current *				
Junction temperature	T_{j}	-40 to +125	°C	
Storage temperature	T_{stg}	-40 to +125	°C	

Note) *: The peak-to-peak value in one cycle of 50 Hz sine wave (non-repetitive)

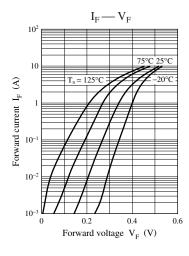


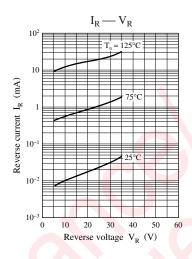
■ Electrical Characteristics T_C = 25°C ± 3°C

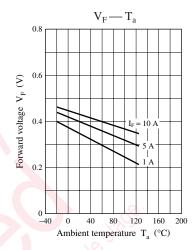
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	$V_{\rm F}$	$I_F = 5 \text{ A}, T_C = 25^{\circ}\text{C}$	1.90		0.47	V
Reverse current	I_R	$V_R = 30 \text{ V}, T_C = 25^{\circ}\text{C}$			3	mA
Thermal resistance (j-c)	R _{th(j-c)}	110 ₁₀ Sill			3.0	°C/W

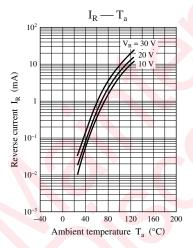
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
 - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
 - 3. Absolute frequency of input and output is 100 MHz.

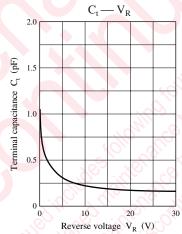
Note) The part number in the parenthesis shows conventional part number.

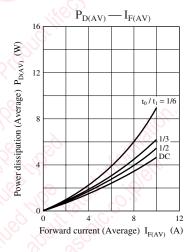


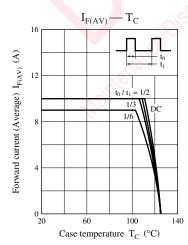












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